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10/792,330	03/02/2004	Hung-Chin Guthrie	HIT1P075/HSJ920040008US1	4407
50535 7	7590 07/12/2006		EXAMINER	
ZILKA-KOTAB, PC			STARK, JARRETT J	
P.O. BOX 721120 SAN JOSE, CA 95172-1120			ART UNIT	PAPER NUMBER
J. I	,		2823	
			DATE MAILED: 07/12/2006	

Please find below and/or attached an Office communication concerning this application or proceeding.

<u>, </u>				<u> </u>
· <u></u>		Application No.	Applicant(s)	
		10/792,330	GUTHRIE ET AL.	
	Office Action Summary	Examiner	Art Unit	
		Jarrett J. Stark	2823	
Period fo	The MAILING DATE of this communicator Reply	ation appears on the cover sheet	with the correspondence ad	dress
WHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR CHEVER IS LONGER, FROM THE MAINS IN THE MAINS IN THE MAINS OF THE M	ILING DATE OF THIS COMMUN 37 CFR 1.136(a). In no event, however, may ication. tory period will apply and will expire SIX (6) M II, by statute, cause the application to become	NICATION. a reply be timely filed ONTHS from the mailing date of this of ABANDONED (35 U.S.C. § 133).	
Status				
1)	Responsive to communication(s) filed	on 26 June 2006		
,	•) This action is non-final.		
,	Since this application is in condition fo	• • • •	atters, prosecution as to the	e merits is
ت. ۳	closed in accordance with the practice			
Disposit	ion of Claims			
5)□ 6)⊠ 7)□	Claim(s) 1-10 and 12-21 is/are pendin 4a) Of the above claim(s) 19-21 is/are Claim(s) is/are allowed. Claim(s) 1-4, 7-10, 12-14, and 16-18 Claim(s) is/are objected to. Claim(s) are subject to restriction	withdrawn from consideration. is/are rejected.		
Applicat	ion Papers			
, —	The specification is objected to by the			
10)[The drawing(s) filed on is/are: a			
	Applicant may not request that any objecti			
11)	Replacement drawing sheet(s) including to the oath or declaration is objected to be			
Priority (under 35 U.S.C. § 119			
a)	Acknowledgment is made of a claim for All b) Some * c) None of: 1. Certified copies of the priority do Some * Copies of the priority do Some * Copies of the priority do Some * Copies of the certified copies of application from the Internations See the attached detailed Office action	ocuments have been received. ocuments have been received ir f the priority documents have be al Bureau (PCT Rule 17.2(a)).	n Application No en received in this National	Stage
Attachmen		∧ □ 1-	ou Summon (PTO 412)	
2) Noti 3) Info	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PT rmation Disclosure Statement(s) (PTO-1449 or P er No(s)/Mail Date	O-948) Paper I	w Summary (PTO-413) No(s)/Mail Date of Informal Patent Application (PT	O-152)

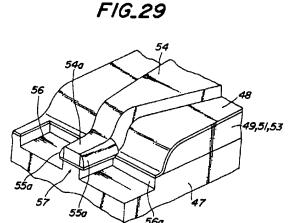
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DETAILED ACTION

Response to Arguments

Applicant's arguments filed 6/26/2006 have been fully considered but they are not persuasive.

In response to the applicant's argument that "lijima does not mention reactive ion milling", <u>lijima</u> discloses that Ion milling is Ion etching. See <u>lijima</u> Col. 11, lines 66-67 "an ion milling is used as this ion beam etching,"



In response to the applicant's argument that <u>lijima</u> does not disclose the combination of CMP and ion milling, → <u>lijima</u> Col. 12 lines 55-56 disclose magnetic layer 54a of Fig. 29 is polished by (CMP).

In response to applicant's argument that there is no suggestion to combine the references, the examiner recognizes that

obviousness can only be established by combining or modifying the teachings of the prior art to produce the claimed invention where there is some teaching, suggestion, or motivation to do so found either in the references themselves or in the knowledge generally available to one of ordinary skill in the art. See *In re Fine*, 837 F.2d 1071, 5 USPQ2d 1596 (Fed. Cir. 1988)and *In re Jones*, 958 F.2d 347, 21 USPQ2d 1941 (Fed. Cir. 1992).

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In this case, as claim 1 is read there is no particular order to when CMP or Ion Milling occurs relative to each other. The claim merely states, "performing a CMP" and "performing a reactive ion mill". Both steps are to remove a portion of the dielectric material. Both process steps are notoriously well known in the art and used remove dielectric material, and both are disclosed and used by <u>lijima</u> when forming the same type of device. Therefore it would be obvious to use both of the known methods while forming the device.

Thus, as the claim is currently written, it is not patentably enforceable over the prior art.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 1-4, 7-10, 12-14, and 16-18 are rejected under 35 U.S.C. 103(a) as being unpatentable over applicant's admitted prior art in view of <u>lijima et al</u>. (US 6,330,743).

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Regarding claim 1, the Applicants admitted prior art (paragraphs [0008-0011] and Figs 1A-B) in view of <u>lijima et al</u> teach a method for manufacturing a magnetic structure on a magnetic write head, comprising:

constructing a photoresist layer having a trench; (applicant's admitted prior art)
depositing a magnetic material into the trench; (applicant's admitted prior art)
removing the photoresist layer; (applicant's admitted prior art)
depositing a dielectric material; (applicant's admitted prior art)

performing a chemical mechanical polish to remove a portion of said dielectric material; (applicant's admitted prior art)

The applicant's prior art does not teach the step of performing a reactive ion mill procedure to remove a portion of dielectric material to expose said magnetic material.

<u>lijima et al</u> teaches the method of performing a reactive ion mill procedure to remove a portion of dielectric material to expose said magnetic material. (<u>lijima</u>, Col. 11 lines 40-43)

Therefore it would be obvious to one of ordinary skill in the art at the time of the invention to combine the teachings of AAPA and <u>lijima et al.</u> to enable the step of reactive ion etching to expose the magnetic material step of lijima et al. to be performed in the process of AAPA because, RIE is a conventionally used method of etching due to its high rate of etching` and selectivity of materials.

portion of the first magnetic layer exposed in the recess is etched such that the recess is dug down over into the first magnetic layer over a part of a whole thickness of the first magnetic layer, and said etching is performed by an ion beam etching such as <u>ion milling</u>.

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Regarding claim 2, the Applicants admitted prior art in view of <u>lijima et al</u> teach a method as in claim 1 further comprising forming a magnetic pole structure over the exposed magnetic material. (Applicant's admitted prior art [0003])

Regarding claim3, the Applicants admitted prior art in view of <u>lijima et al</u> teach a method as in claim 1 wherein said constructing a photoresist trench further comprises:

depositing photoresist; and

performing a deep ultraviolet photolithography on the photoresist.

(Applicants admitted prior art paragraphs [0008-0011] and Figs 1A-B)

Regarding claim 4, the Applicants admitted prior art in view of <u>lijima et al</u> teach a method as in claim 1, wherein said depositing said magnetic material comprises electroplating. (Applicants admitted prior art paragraph [0003])

Regarding claim 7, the Applicants admitted prior art in view of <u>lijima et al</u> teach a method as in claim 1, wherein said magnetic material comprises NiFe. (Applicants admitted prior art paragraph [0004])

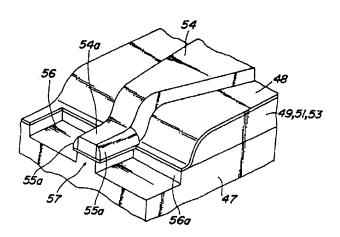
Regarding claim 8, the Applicants admitted prior art in view of <u>lijima et al</u> teach a method as in claim 2, wherein said magnetic pole structure comprises NiFe.

(Applicants admitted prior art paragraph [0004])

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Regarding claims 9,17, and 18 the Applicants admitted prior art in view of <u>lijima</u> et al teach a method as in claim 1 (regarding claims 20 & 21- the structure of claim 19), wherein said reactive ion milling procedure forms a recession of between 0 and 0.3 microns between said magneticstructure and an upper surface of said alumina. <u>lijima</u> teaches using ion etching to form the recession (56) in Fig 29.

FIG_29



It would have been obvious to one of ordinary skill in the art of making semiconductor devices to determine the workable or optimal value for the depth of the recession through routine experimentation and optimization to obtain optimal or desired device performance because the depth of the recession is a result-effective variable and there is no evidence indicating that it is critical or produces any unexpected results and it has been held that it is not inventive to discover the optimum or workable ranges of a result-effective variable within given prior art conditions by routine experimentation. See MPEP 2144.05

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Given the teaching of the references, it would have been obvious to determine the optimum thickness, temperature as well as condition of delivery of the layers involved. See In re Aller, Lacey and Hall (10 USPQ 233-237) "It is not inventive to discover optimum or workable ranges by routine experimentation." Note that the specification contains no disclosure of either the critical nature of the claimed ranges or any unexpected results arising therefrom. Where patentability is said to be based upon particular chosen dimensions or upon another variable recited in a claim, the Applicant must show that the chosen dimensions are critical. In re Woodruff, 919 f.2d 1575, 1578, 16 USPQ2d 1934, 1936 (Fed. Cir. 1990).

Any differences in the claimed invention and the prior art may be expected to result in some differences in properties. The issue is whether the properties differ to such an extent that the difference is really unexpected. In re Merck & Co., 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986).

Appellants have the burden of explaining the data in any declaration they proffer as evidence of non-obviousness. Ex parte Ishizaka, 24 USPQ2d 1621, 1624 (Bd. Pat. App. & Inter. 1992).

An Affidavit or declaration under 37 CFR 1.132 must compare the claimed subject matter with the closest prior art to be effective to rebut a prima facie case of obviousness. In re Burckel, 592 F.2d 1175, 201 USPQ 67 (CCPA 1979).

Regarding claims 10 & 12, the Applicants admitted prior art in view of <u>lijima et al</u> teach a method as in claim 1 wherein said magnetic structure has a width sigma of less

than 10 nanometers.

lijima teachs in Col. 1 lines 50-56, the "performance of a recording head has been also required to be improved. In order to increase a surface recording density, it is necessary to make a track density on a magnetic record medium as high as possible.

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For this purpose, a width of a pole portion at the air bearing surface has to be reduced to a value within a range from several micron meters to several sub-micron meters."

Therefore it would have been obvious to one of ordinary skill in the art of making semiconductor devices to determine the workable or optimal value for the width of the magnetic structure through routine experimentation and optimization to obtain optimal or desired device performance because the width of the magnetic structure is a resulteffective variable and there is no evidence indicating that it is critical or produces any unexpected results and it has been held that it is not inventive to discover the optimum or workable ranges of a result-effective variable within given prior art conditions by routine experimentation. See MPEP 2144.05

Regarding claim 13, the Applicants admitted prior art in view of lijima et al teach a method as in claim 1 wherein said dielectric material is alumina (Al₂O₃). (Applicants admitted prior art paragraph [0005] & lijima, Col. 2, line 11)

Regarding claim 14, the Applicants admitted prior art in view of lijima et al teach a method as in claim 1 wherein said magnetic structure is a P3 pedestal of a magnetic pole. (<u>lijima</u>, Fig. 29 (54))

Regarding claim 16, the Applicants admitted prior art in view of lijima et al teach a method as in claim 1 wherein said reactive ion mill is performed sufficiently to create a

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recess between an upper surface of said magnetic structure and an upper surface of said dielectric material. (<u>lijima</u>, Fig. 29)

Claims 5-6 and 15 are rejected under 35 U.S.C. 103(a) as being unpatentable over applicant's admitted prior art in view of <u>lijima et al</u>. (US 6,330,743) in further view of Otsuku, (US 2001/0005297).

Regarding claim 5, the Applicants admitted prior art in view of <u>lijima et al</u> teach a method as in claim 1, wherein said depositing said magnetic material comprises electroplating said magnetic material.

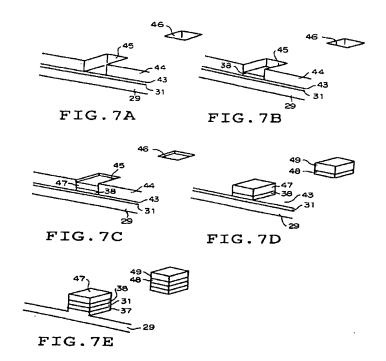
The combined references fail to disclose the method of terminating said electroplating before said magnetic material reaches an upper opening in said trench formed in said photoresist layer.

Otsuka teaches and shows in Figures & 7A-C the method of stopping the electroplating before the magnetic reaches the upper opening of the trench. (Otsuka, [0038-39])

Therefore it would be obvious to one of ordinary skill in the art at the time of the invention to combine the teachings of AAPA, lijima and Otsuka to enable the step of stopping the electroplating before the magnetic reaches the upper opening of the trench

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of Otsuku to be performed in the process of the combination, "so as to suppress or totally prevent a magnetic blur in a resulting thing film magnetic head element". (Otsuka, [0038])



In this manner, the upper magnetic pole piece 38 is formed within the void 45. The thickness of the deposited magnetic layer is set larger than 0.5 micrometers, for example, so as to suppress or totally prevent a magnetic blur in a resulting thin film magnetic head element 26. (Otsuka, [0038])

Regarding claim 6, the Applicants admitted prior art in view of <u>lijima et al</u> in further view of <u>Otsuka</u> teach a method as in claim 1, wherein said trench includes a flared portion (Applicant's prior art, [009], fig 1, (106)), and wherein said depositing said magnetic material comprises electroplating said magnetic material, and terminating said

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electroplating before said magnetic material reaches said flared portion formed in said trench. (Otsuka, Figures & 7A-C)

Regarding claim 15, the Applicants admitted prior art in view of <u>lijima et al</u> in further view of <u>Otsuka</u> teach a method as in claim 1 wherein said reactive ion mill is performed in an atmosphere comprising CHF₃. (<u>Otsuka</u>, paragraph [0046])

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jarrett J. Stark whose telephone number is (571) 272-6005. The examiner can normally be reached on Monday - Thursday 7:00AM - 5:30PM.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith can be reached on (571) 272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

JJS July 1, 2006

> MICHELLE ESTRADA PRIMARY EXAMINER